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## **AAP Gen 7 (TO-240AA) Power Modules Standard Diodes, 100 A**



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	100 A					
Type	Modules - diode, high voltage					
Package	AAP Gen 7 (TO-240AA)					
Circuit configuration	Two diodes doubler circuit, two diodes common cathode, two diodes common anode, single diode					

#### **MECHANICAL DESCRIPTION**

The AAP Gen 7 (TO-240AA), new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### **FEATURES**

- High voltage
- · Industrial standard package
- UL approved file E78996



- · Low thermal resistance
- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### **BENEFITS**

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- · Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
1		100	А				
I <sub>F(AV)</sub>	T <sub>C</sub>	112	°C				
I <sub>F(RMS)</sub>		157					
	50 Hz	2020	Α				
IFSM	60 Hz	2115					
l <sup>2</sup> t	50 Hz	20.41	kA <sup>2</sup> s				
1-1	60 Hz	18.63	KA-S				
I <sup>2</sup> √t		204.1	kA²√s				
V <sub>RRM</sub>	Range	400 to 1600	V				
T <sub>Stg</sub>		-40 to +150	°C				
T <sub>J</sub>		-40 to +150	°C				

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#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = 150 °C mA				
	04	400	500					
	06	600	700					
	08	800	900					
VS-VSK.91	10	1000	1100	10				
	12	1200	1300					
	14	1400	1500					
	16	1600	1700					

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I <sub>F(AV)</sub>	180° condu	180° conduction, half sine wave			A °C
Maximum RMS forward current	I <sub>F(RMS)</sub>				112 157	
	( )	t = 10 ms	No voltage		2020	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		2115	Α
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	_	1700	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1780	
	l <sup>2</sup> t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	20.41	kA <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms	reapplied		18.63	
Maximum I-t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		14.44	
		t = 8.3  ms	reapplied		13.18	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	204.1	kA²√s
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	$I_{F(AV)}$ , $T_J = T_J$ maximum	0.76	V
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			0.89	V
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum			2.4	mΩ
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			2.05	1115.2
Maximum forward voltage drop	$V_{FM}$	$I_{FM} = \pi \times I_{F(a)}$	<sub>AV)</sub> , T <sub>J</sub> = 25 °C,	t <sub>p</sub> = 400 μs square wave	1.55	V

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak reverse leakage current	I <sub>RRM</sub>	T <sub>J</sub> = 150 °C	10	mA			
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V			

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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Junction and storage temper	erature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C			
Maximum internal thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.22	°C/W			
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>	Mounting surface flat, smooth, and greased	0.1	C/VV			
Mounting torque ± 10 % busbar			A mounting compound is recommended and the	4	Nm			
			torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	3	INITI			
Approximate weight				75	g			
Approximate weight	Approximate weight			2.7	oz.			
Case style			JEDEC®	AAP Gen 7	(TO-240AA)			

AR CONDUCTION PER JUNCTION											
DEVICES	8	SINE HALF	WAVE CO	NDUCTION	7	RECTANGULAR WAVE CONDUCTION				NC	UNITS
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.91	0.057	0.068	0.087	0.12	0.177	0.045	0.073	0.093	0.123	0.178	°C/W

#### Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

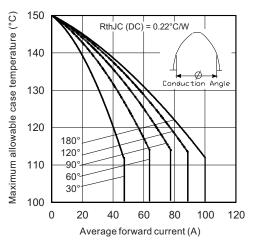


Fig. 1 - Current Ratings Characteristics

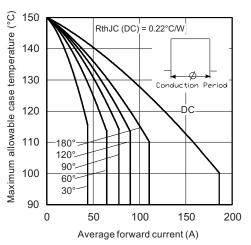


Fig. 2 - Current Ratings Characteristics

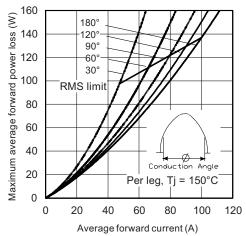


Fig. 3 - Forward Power Loss Characteristics

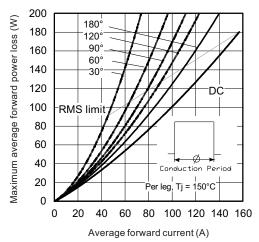
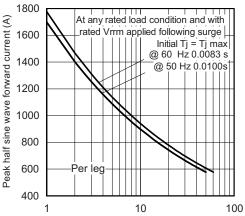


Fig. 4 - On-State Power Loss Characteristics



Number of equal amplitude half cycle current pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

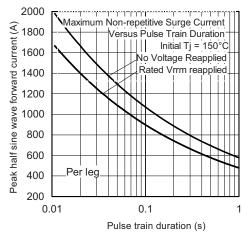


Fig. 6 - Maximum Non-Repetitive Surge Current



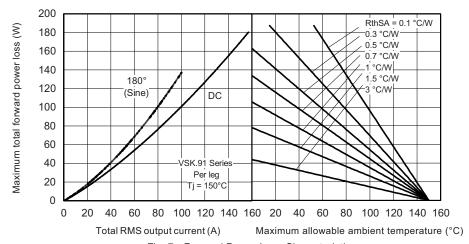


Fig. 7 - Forward Power Loss Characteristics

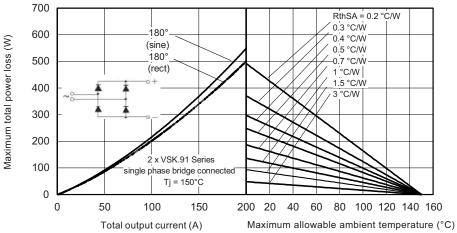


Fig. 8 - Forward Power Loss Characteristics

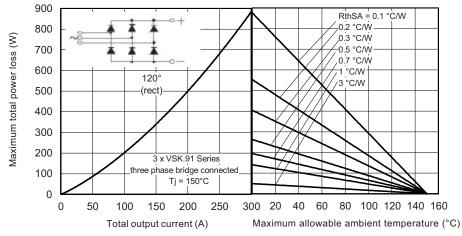


Fig. 9 - Forward Power Loss Characteristics

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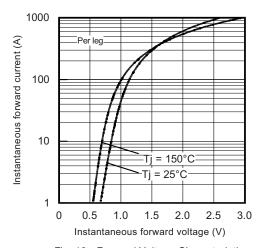


Fig. 10 - Forward Voltage Characteristics

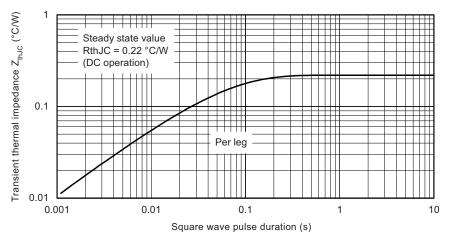
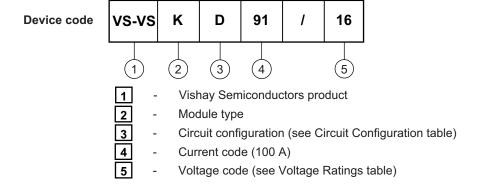


Fig. 11 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**



#### Note

• To order the optional hardware go to <a href="https://www.vishay.com/doc?95172">www.vishay.com/doc?95172</a>

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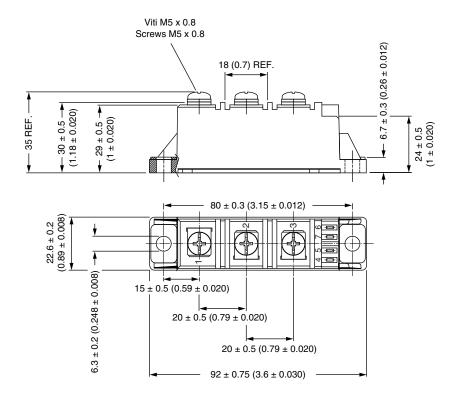
CIRCUIT CONFIGURATION		
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Two diodes doubler circuit	D	VSKD  (1) ~ (2) ~ (3)
Two diodes common cathode	С	VSKC  (1) 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0
Two diodes common anode	J	VSKJ  (1) (2) - (3)
Single diode	E	VSKE  (1) 0

LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95369

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### **ADD-A-PAK Generation VII - Diode**

### **DIMENSIONS** in millimeters (inches)





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